

Name

SAI RAM INSTITUTE OF TECHNOLOGY

An ISO 9001: 2008 Certified Institution

Sai Leo Nagar, West Tambaram, Chennai - 44. www.sairamit.edu.in

DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

: M. Pown

Designation	: AP – III
Email	: pown.ece@sairamit.edu.in
Qualification	: M. E., Ph.D
Specialization	: VLSI Design
Research Interest	: Semiconductor Devices and Circuits
Experience in years	: Teaching UG _ PG _ Industry -
No. of Workshop/Conferences/ FDP attended	: Workshop 4 Conferences 3 FDP 4
No. of Workshop/Conferences/ FDP Organized	: Workshop - Conferences - FDP -
Professional Membership	 IEEE (98101854) IETE (AM-235828) IAENG (237751)
	National : -
Publications	International: 8
	Book : -
Research Funded Projects	-
Patents	-
Achievements	-
Any Other Information	-

List of Publications:-

- 1. **M. Pown**, S. Sandeep and B. Lakshmi, "Investigation of Homo and Hetero-Junction Double-Gate Tunnel-FET-Based Adiabatic Inverter Circuits", IETE Journal of Research, pp. 1-9, Dec 2020. [Indexed in: SCI, Scopus. **IF: 1.125**]
- 2. **M. Pown** and B. Lakshmi, "Investigation of Radiation Hardened TFET SRAM cell for Mitigation of Single Event Upset", IEEE Journal of the Electron Devices Society, vol. 8, June 2020. [Indexed in: SCI, Scopus. **IF: 2.555**]
- 3. **M. Pown** and B. Lakshmi, "Stability analysis of homo and hetero-junction based TFET SRAMs", International Journal of Scientific and Technology Research, vol. 9, no. 11, pp. 102-108, June 2020.
- 4. **M. Pown**, B. Lakshmi, "Performance Analysis of InAs and GaSb-InAs Based Independent Gate Tunnel Field Effect Transistor RF Mixers", Journal of Computational Electronics (Springer) vol. 16, no. 3, pp. 676-684, Sep 2017. [Indexed in: SCI, Scopus. **IF: 1.532**]
- 5. S. Poorvasha, **M. Pown**, B. Lakshmi, "Tunnel Field Effect Transistors for Digital and Analog Applications: A Review", Indian Journal of Science and Technology, vol. 10, no. 13, pp. 1-7, April 2017.
- 6. **M. Pown** and B. Lakshmi, "Investigation of ft and fmax in Si and Si1-xGex based single and dual material double-gate Tunnel FETs for RF applications", Advances in Natural Sciences: Nanoscience and Nanotechnology (IOP Science), vol. 7, No.2, pp.1-7, April 2016. [Scopus CiteScore: 4.9]
- 7. Viral Gokani, Roop Narayan Goswami, **M. Pown**, B. Lakshmi, "Impact of Underlap Variation on the Analog Parameters of High-K Gate Dielectric based Double Gate Tunnel FETs", International Journal of Applied Engineering Research, Vol-10, No-92, pp. 268-273, 2015.
- 8. D. Selvathi, **M. Pown**, and S. Manjula, "Design and Analysis of UWB Down-Conversion Mixer with Linearization Techniques", WSEAS Transactions on Circuits and Systems, vol. 13, pp. 202-207, July 2014.

Workshop / Conferences / FDP Attended:-

- 1. Participated in the 19th Hands-on Training on "Photovoltaics and Micro and Nano Characterization Techniques" conducted at IISc, Bangalore, from 3-12 February 2015.
- 2. Participated in the INUP Familiarization Workshop on "Nanofabrication Technologies" conducted at IISc, Bangalore, 28-30 January 2015.
- 3. Participated workshop on Applications of Microcontroller in Tamilnadu College of Engineering (TCE), Coimbatore.
- 4. Participated workshop on Embedded System in TCE, Coimbatore.

FDP:

- 1. Attended Three day online FDP on eSim organized by VIT, Chennai, 2020.
- 2. Attended one week FDP on Python Programming organized by Geethanjali Institute of Science and Technology, Nellore, AP, 2020.
- 3. Attended one week online FDP on "Signals, Systems and Transform Techniques" organized by Maturi Venkata Subba Rao Engineering College, Hyderabad, November 2021.
- 4. Attended Refresher/Induction programme on "FPGA for Low Power IoT" organized by SRM Valliammai Engineering College, Chennai, December 2021.

International Conference

- 1. **M. Pown**, B. Lakshmi, "Effect of the Geometrical Parameters on ft in Si and Si1-xGex Dual Material Double-Gate TFETs", IEEE International Conference on Electronics and Communication Systems (ICECS 2016), pp. 239-243.
- 2. Viral Gokani, Roop Narayan Goswami, **M. Pown**, B. Lakshmi, "Impact of Underlap Variation on the Analog Parameters of High-K Gate Dielectric based Double Gate Tunnel FETs", Proceedings of International Conference on Researches in Science, Management and Engineering (ICRSME 2016), 18-19 February 2016.
- 3. D. Selvathi and **M. Pown**, "Design of Band Pass Filter using Active Inductor for RF receiver Frontend", IEEE International Conference on Communication and Network Technologies (ICCNT), pp. 296-301, December 2014.